

FEATURES

- 27 dB Gain
- +24 dBm Linear Output Power
- 2.3 % EVM (OFDM Modulation)
- +6 V Supply
- High Efficiency
- Integrated 1-bit 20 dB Step Attenuator
- Integrated Output Power Detector
- 50 Ω Matched RF Ports
- RoHS Compliant 4.5 mm x 4.5 mm x 1.4 mm Surface Mount Module

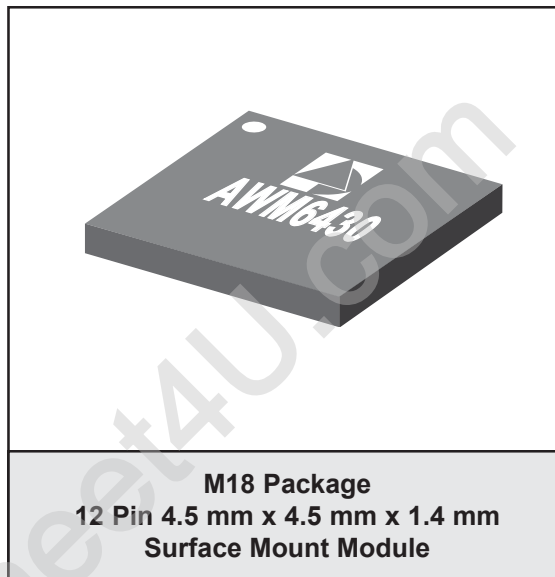
APPLICATIONS

- WiMAX transceivers that support the IEEE 802.16-2004 and ETSI EN301-021 standards
- Broadband Wireless Applications (BWA)

PRODUCT DESCRIPTION

The ANADIGICS AWM6430 WiMAX Power Amplifier is a high performance device that delivers exceptional linearity and efficiency at high levels of output power. Designed to operate in the 3.5 GHz band, it supports the IEEE 802.16-2004 and ETSI EN301-021 wireless standards.

The device requires only a single +6 V supply and a low-current reference input. An integrated detector can be used to monitor output power, and an integrated 20 dB step attenuator enables gain



control. No external circuits are required for biasing or RF impedance matching, thus reducing external component costs and facilitating circuit board designs.

The AWM6430 is manufactured using advanced InGaP HBT technology that offers state-of-the-art reliability, temperature stability and ruggedness. It is optimized for use in a 50 Ω system, and is offered in a 4.5 mm x 4.5 mm x 1.4 mm surface mount module.

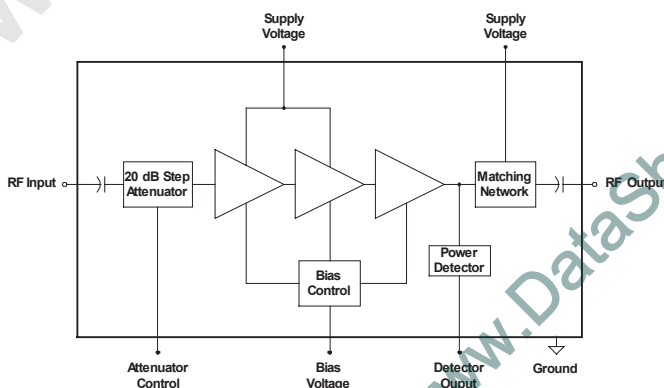


Figure 1: Functional Block Diagram

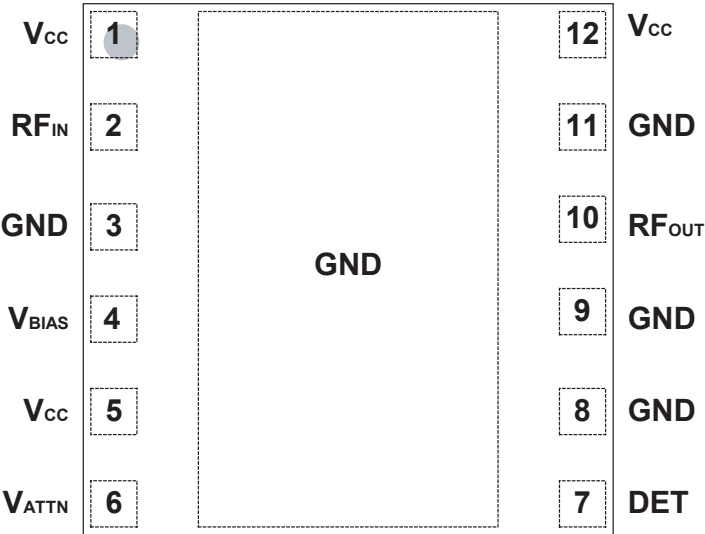


Figure 2: Pinout (X-ray Top View)

Table 1: Pin Description

PIN	NAME	DESCRIPTION
1	V _{CC}	Supply Voltage
2	RF _{IN}	RF Input
3	GND	Ground
4	V _{BIAS}	Bias/Shutdown
5	V _{CC}	Supply Voltage
6	V _{ATTN}	Attenuator Control
7	DET	Detector Output
8	GND	Ground
9	GND	Ground
10	RF _{OUT}	RF Output
11	GND	Ground
12	V _{CC}	Supply Voltage

ELECTRICAL CHARACTERISTICS

Table 2: Absolute Minimum and Maximum Ratings

PARAMETER	MIN	MAX	UNIT	COMMENTS
Supply Voltage (V_{CC})	0	+6.5	V	
Bias Voltage (V_{BIAS})	0	+3.3	V	
Attenuator Control Voltage (V_{ATTN})	0	+3.7	V	
RF Input Power	-	0	dBm	OFDM modulated signal
Storage Temperature	-40	+150	°C	

Stresses in excess of the absolute ratings may cause permanent damage. Functional operation is not implied under these conditions. Exposure to absolute ratings for extended periods of time may adversely affect reliability.

Table 3: Operating Ranges

PARAMETER	MIN	TYP	MAX	UNIT	COMMENTS
Operating Frequency (f)	3400	-	3600	MHz	
Supply Voltage (V_{CC})	+5.0	-	+6.0	V	
Bias Voltage (V_{BIAS})	- 0	+3.0 -	- +0.7	V	PA"on" PA"shut down"
Attenuator Control Voltage (V_{ATTN}) Logic High Logic Low	+2.3 0	- -	+3.7 +0.7	V	Attenuator enabled Nominal gain
RF Output Power (P_{OUT})	-	+24	-	dBm	
Case Temperature (T_C)	-40	-	+85	°C	

The device may be operated safely over these conditions; however, parametric performance is guaranteed only over the conditions defined in the electrical specifications.

Table 4: Electrical Specifications
(T_C = +25 °C, V_{CC} = +6.0 V, V_{BIAS} = +3.0 V, f = 3.5 GHz, 50 Ω system)

PARAMETER	MIN	TYP	MAX	UNIT	COMMENTS
Gain	-	27	-	dB	
Attenuator Step	-	20	-	dB	
Output Power Meets Spectrum Mask	+24	-	-	dBm	ETSI EN301-021 Type G
EVM (OFDM Waveform)	-	2.3	-	%	at +24 dBm P _{OUT}
Output P1dB	-	+31	-	dBm	CW
Output IP3	-	+43	-	dBm	two tones, +21 dBm out per tone
Harmonics	-	-20	-	dBm	at +24 dBm P _{OUT}
Power-Added Efficiency	-	12.8	-	%	at +24 dBm P _{OUT}
Power Detector Voltage at +24 dBm P _{OUT} at +14 dBm P _{OUT}	- -	+2.6 +0.6	- -	V	High impedance load
Quiescent Current	-	105	-	mA	
Current Consumption V _{CC} V _{BIAS} V _{ATTN}	- - -	325 6.8 0.2	- - -	mA	P _{OUT} = +24 dBm Logic High = +3.3 V
Leakage Current	-	1.7	-	mA	PA shut down

PERFORMANCE DATA

Figure 3: Gain vs. Output Power
($T_C = +25\text{ }^\circ\text{C}$, $V_{CC} = +6.0\text{ V}$, $V_{BIAS} = +3.0\text{ V}$,
 $f = 3.5\text{ GHz}$, OFDM Modulation)

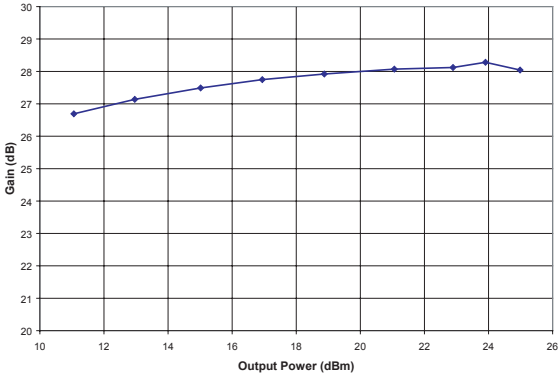


Figure 4: Gain vs. Frequency
($T_C = +25\text{ }^\circ\text{C}$, $V_{CC} = +6.0\text{ V}$, $V_{BIAS} = +3.0\text{ V}$,
 $P_{OUT} = +24\text{ dBm}$, OFDM Modulation)

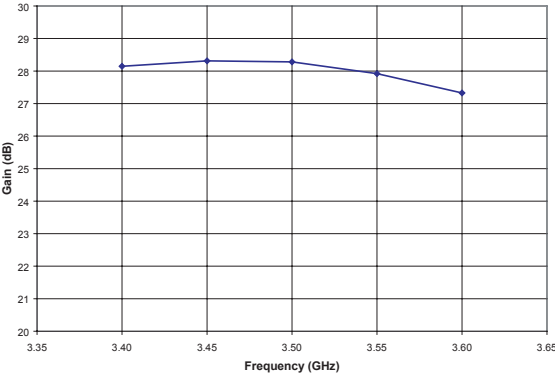


Figure 5: EVM vs. Output Power
($T_C = +25\text{ }^\circ\text{C}$, $V_{CC} = +6.0\text{ V}$, $V_{BIAS} = +3.0\text{ V}$,
OFDM Modulation)

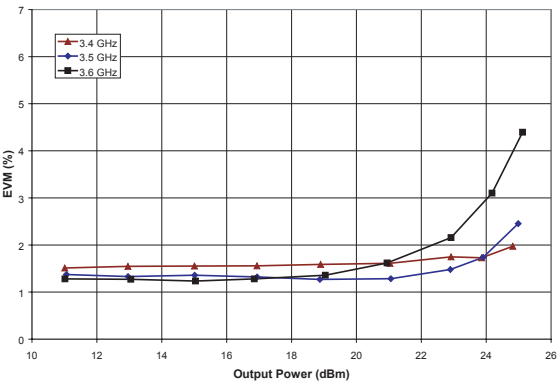


Figure 6: EVM vs. Frequency
($T_C = +25\text{ }^\circ\text{C}$, $V_{CC} = +6.0\text{ V}$, $V_{BIAS} = +3.0\text{ V}$,
OFDM Modulation)

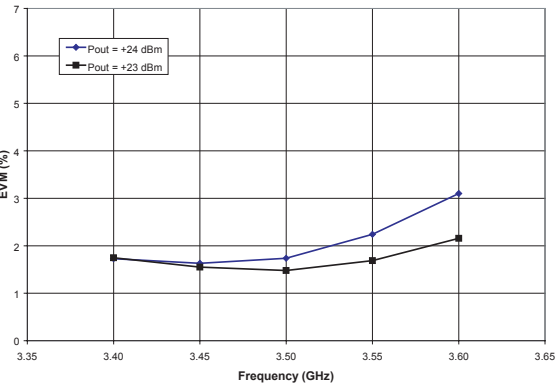


Figure 7: Detector Voltage vs. Output Power
 ($T_C = +25\text{ }^\circ\text{C}$, $V_{CC} = +6.0\text{ V}$, $V_{BIAS} = +3.0\text{ V}$,
 $f = 3.5\text{ GHz}$, OFDM Modulation)

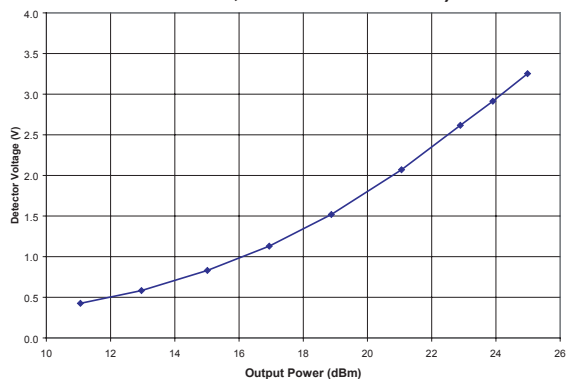


Figure 8: Detector Voltage vs. Frequency
 ($T_C = +25\text{ }^\circ\text{C}$, $V_{CC} = +6.0\text{ V}$, $V_{BIAS} = +3.0\text{ V}$,
 OFDM Modulation)

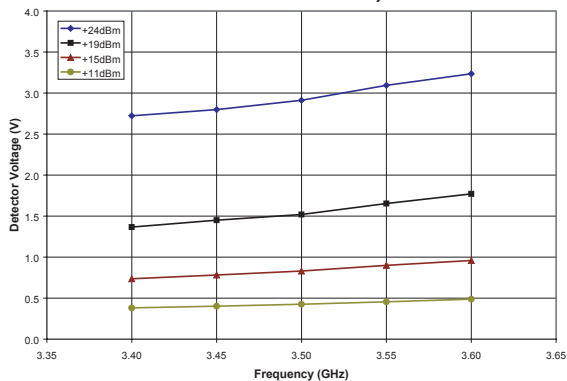
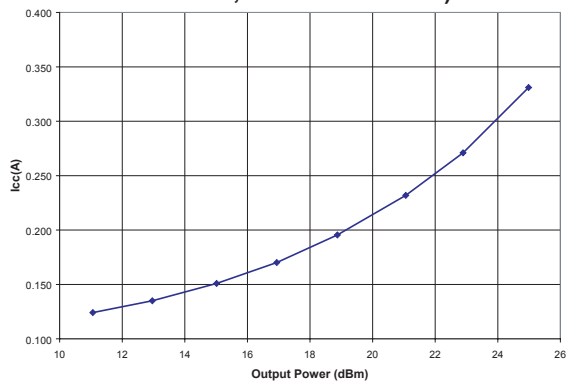


Figure 9: Supply Current vs. Output Power
 ($T_C = +25\text{ }^\circ\text{C}$, $V_{CC} = +6.0\text{ V}$, $V_{BIAS} = +3.0\text{ V}$,
 $f = 3.5\text{ GHz}$, OFDM Modulation)



APPLICATION INFORMATION

Transmit Disable and Attenuator Control

The power amplifier is disabled by setting V_{BIAS} below +0.7 V. The step attenuator is enabled by applying a logic high to V_{ATTN} ; the PA exhibits nominal gain when a logic low is applied to V_{ATTN} .

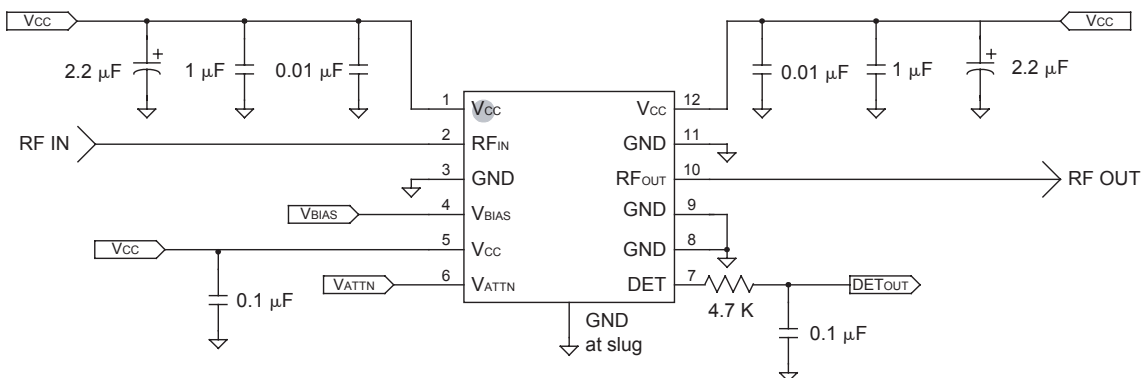
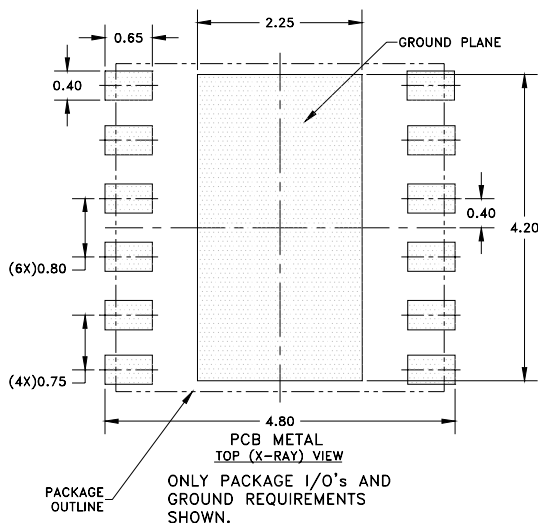


Figure 10: Application Circuit



NOTES:

(1) UNLESS SPECIFIED, DIMENSIONS
ARE SYMMETRICAL ABOUT CENTER
LINES SHOWN.

(2) DIMENSIONS IN MILLIMETERS.

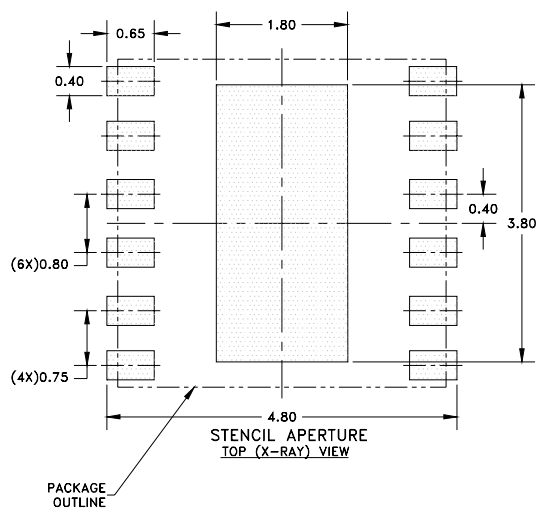
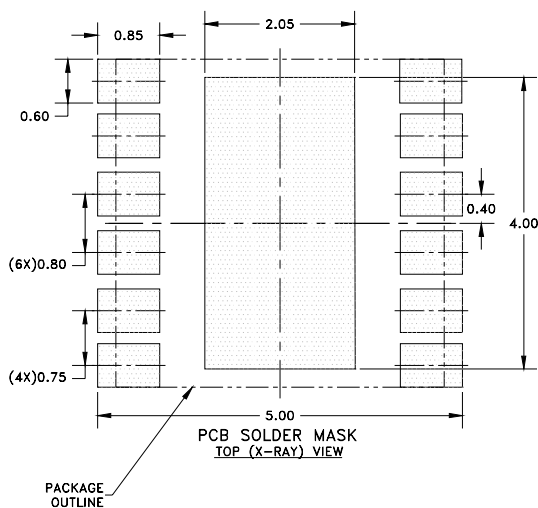
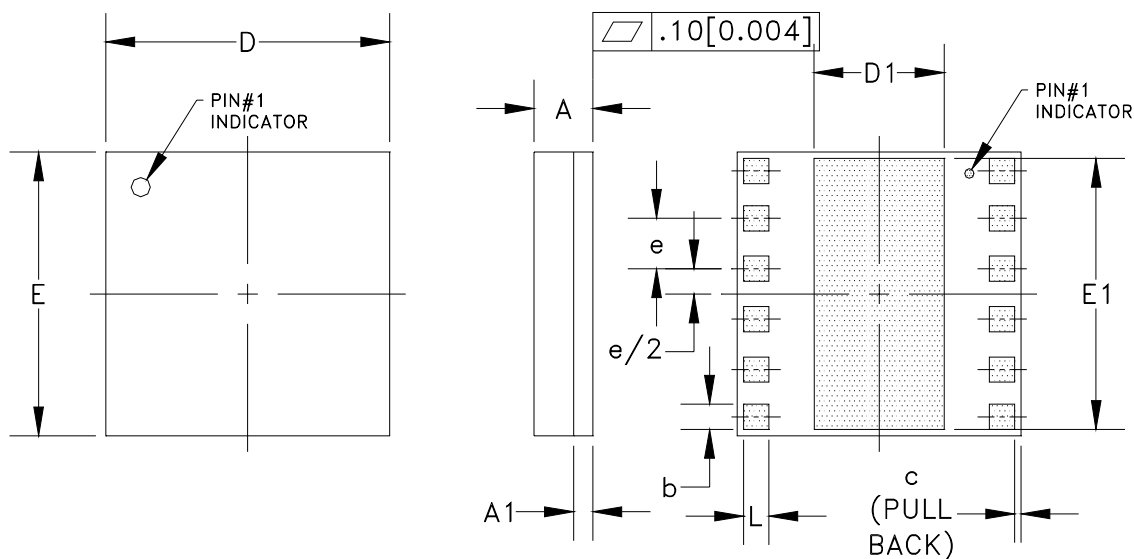


Figure 11: Land Pattern

PACKAGE OUTLINE



s_{WBOL}	MILLIMETERS			INCHES			NOTE
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	
A	1.26	1.41	1.56	0.049	0.055	0.061	—
A1	—	0.30	—	—	0.012	—	—
b	0.32	—	0.48	0.013	—	0.019	3
c	—	0.10	—	—	0.004	—	—
D	4.38	4.50	4.62	0.172	0.177	0.182	—
D1	1.97	—	2.13	0.078	—	0.084	—
E	4.38	4.50	4.62	0.172	0.177	0.182	—
E1	4.22	—	4.38	0.166	—	0.172	—
e	—	0.80	—	—	0.032	—	3
L	0.32	—	0.48	0.013	—	0.019	3

NOTES:

1. CONTROLLING DIMENSIONS: MILLIMETERS
2. UNLESS SPECIFIED TOLERANCE=±0.076[0.003].
3. PADS (INCLUDING CENTER) SHOWN UNIFORM SIZE FOR REFERENCE ONLY. ACTUAL PAD SIZE AND LOCATION WILL VARY WITHIN MIN. AND MAX. DIMENSIONS ACCORDING TO SPECIFIC LAMINATE DESIGN.

Figure 12: M18 Package Outline - 12 Pin 4.5 mm x 4.5 mm x 1.4 mm Surface Mount Module

NOTES



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WARNING

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